## DESCRIPTIOn

The RH1009 is a general purpose 2.5 V shunt regulator diode designed to operate over a wide current range while maintaining good stability with time and temperature. The adjust terminal allows either temperature coefficient to be minimized or the reference voltage to be adjusted without changing the temperature coefficient. Because it operates as a shunt regulator it can be used equally well as a positive or negative reference.
The wafer lots are processed to Linear Technology's inhouse Class $S$ flow to yield circuits usable in stringent military applications.

## absolute maximum ratings

Reverse Breakdown Current ................................ 20 mA
Forward Current.................................................. 10mA
Operating Temperature Range ............. $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Storage Temperature Range $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ Lead Temperature (Soldering, 10 sec ) $\qquad$

## BURN-In CIRCUIT



## TABLE 1: ELECTRICAL CHAßACTERISTICS (Preirradiation)

| SYMBOL | PARAMETER | CONDITIONS | NOTES | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  |  | $\begin{aligned} & \text { SUB- } \\ & \text { GROUP } \end{aligned}$ | $\begin{gathered} -55^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{J}} \leq 150^{\circ} \mathrm{C} \\ \text { MIN TYP MAX } \end{gathered}$ |  |  | $\begin{aligned} & \text { SUB- } \\ & \text { GROUP } \end{aligned}$ | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP | MAX |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{Z}}$ | Reverse Breakdown Voltage | $\mathrm{I}_{\mathrm{R}}=1 \mathrm{~mA}$ |  | 2.495 |  | 2.505 | 1 |  |  |  |  | V |
| $\frac{\Delta V_{Z}}{\Delta I_{\mathrm{R}}}$ | Reverse Breakdown Voltage Change with Current | $400 \mu \mathrm{~A} \leq \mathrm{I}_{\mathrm{R}} \leq 10 \mathrm{~mA}$ |  |  |  | 6 | 1 |  |  | 10 | 2,3 | mV |
| $\mathrm{r}_{\mathrm{Z}}$ | Reverse Dynamic Impedance | $\mathrm{I}_{\mathrm{R}}=1 \mathrm{~mA}$ | 1 |  |  | 0.6 |  |  |  | 1 |  | $\Omega$ |
| $\Delta \mathrm{V}_{\mathrm{Z}}$ | Temperature Stability |  | 1 |  |  |  |  |  |  | 15 |  | mV |
| $\frac{\Delta \mathrm{V}_{\mathrm{Z}}}{\Delta \mathrm{Time}}$ | Long Term Stability | $\begin{aligned} & \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \pm 0.1^{\circ} \mathrm{C}, \\ & \mathrm{I}_{\mathrm{R}}=1 \mathrm{~mA} \end{aligned}$ |  |  | 20 |  |  |  |  |  |  | ppm/kHr |

TABLE 1A: ELECTRICAL CHARACTERISTICS (Posifradiaion) (Nole 2)

| SYMBOL | PARAMETER | CONDITIONS | NOTES | 10KRAD(Si) |  | 20KRAD(Si) |  | 50KRAD(Si) |  | 100KRAD(Si) |  | 200KRAD(Si) |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX |  |
| $\mathrm{V}_{\text {Z }}$ | Reverse Breakdown Voltage | $\mathrm{I}_{\mathrm{R}}=1 \mathrm{~mA}$ |  | 2.495 | 2.505 | 2.495 | 2.505 | 2.495 | 2.505 | 2.495 | 2.505 | 2.495 | 2.505 | V |
| $\frac{\Delta V_{Z}}{\Delta I_{Z}}$ | Reverse Breakdown Voltage Change with Current | $400 \mu \mathrm{~A} \leq \mathrm{I}_{\mathrm{R}} \leq 10 \mathrm{~mA}$ |  |  | 6 |  | 6 |  | 8 |  | 10 |  | 12 | mV |
| $\mathrm{r}_{\mathrm{Z}}$ | Reverse Dynamic Impedance | $\mathrm{I}_{\mathrm{R}}=1 \mathrm{~mA}$ | 1 |  | 0.6 |  | 0.6 |  | 0.8 |  | 1.0 |  | 1.4 | $\Omega$ |

Note 1: Guaranteed by design, characterization or correlation to other
Note 2: $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted. tested parameters.

## TOTAL DOSE BIAS CIRCUIT



## TAßLE 2: ELECTRICAL TEST REQUIRGMEחTS

| MIL-STD-883 TEST REQUIREMENTS | SUBGROUP |
| :--- | :---: |
| Final Electrical Test Requirements (Method 5004) | $1^{*}, 2,3$ |
| Group A Test Requirements (Method 5005) | $1,2,3$ |
| Group C and D End Point Electrical Parameters <br> (Method 5005) | 1 |

* PDA Applies to subgroup 1. See PDA Test Notes.

PDA Test Notes
The PDA is specified as $5 \%$ based on failures from group A, subgroup 1, tests after cooldown as the final electrical test in accordance with method 5004 of MIL-STD-883 Class B. The verified failures of group A, subgroup 1, after burn-in divided by the total number of devices submitted for burnin in that lot shall be used to determine the percent for the lot. Linear Technology Corporation reserves the right to test to tighter limits than those given.

## TYPICAL PERFORMANCE CHARACTERISTICS



RH1009 G01

## Reverse Breakdown Voltage


I.D. No. 66-10-0174 Rev. B 0497

